

2N2484

NPN SILICON TRANSISTOR



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DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N2484 type is an NPN silicon transistor designed for low noise amplifier applications.



TO-18 CASE

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

Collector-Base Voltage	V_{CBO}	60	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Continuous Collector Current	I_C	50	mA
Power Dissipation	P_D	360	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +200	$^\circ\text{C}$
Thermal Resistance	Θ_{JA}	486	$^\circ\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=45\text{V}$		10	nA
I_{CBO}	$V_{CB}=45\text{V}, T_A=150^\circ\text{C}$		10	μA
I_{CEO}	$V_{CE}=5.0\text{V}$		2.0	nA
I_{EBO}	$V_{EB}=5.0\text{V}$		10	nA
BV_{CBO}	$I_C=10\mu\text{A}$	60		V
BV_{CEO}	$I_C=10\text{mA}$	60		V
BV_{EBO}	$I_E=10\mu\text{A}$	6.0		V
$V_{CE(\text{SAT})}$	$I_C=1.0\text{mA}, I_B=100\mu\text{A}$		0.35	V
$V_{BE(\text{ON})}$	$V_{CE}=5.0\text{V}, I_C=100\mu\text{A}$	0.5	0.7	V
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\mu\text{A}$	30		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=10\mu\text{A}$	100	500	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=10\mu\text{A}, T_A=-55^\circ\text{C}$	20		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=100\mu\text{A}$	175		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=500\mu\text{A}$	200		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}$	250		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=10\text{mA}$		800	
h_{fe}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$	150	900	
f_T	$V_{CE}=5.0\text{V}, I_C=50\mu\text{A}, f=5.0\text{MHz}$	15		MHz
f_T	$V_{CE}=5.0\text{V}, I_C=0.5\text{mA}, f=30\text{MHz}$	60		MHz
h_{ie}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$	3.5	24	$\text{k}\Omega$
h_{oe}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$		40	μS
h_{re}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}, f=1.0\text{kHz}$		800	$\times 10^{-6}$
C_{ob}	$V_{CB}=5.0\text{V}, I_E=0, f=140\text{kHz}$		6.0	pF
C_{ib}	$V_{EB}=0.5\text{V}, I_C=0, f=140\text{kHz}$		6.0	pF

R1 (30-May 2012)

2N2484

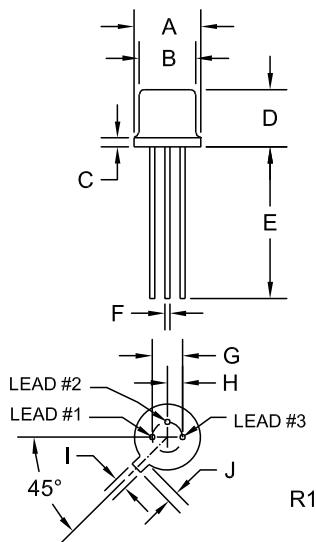
NPN SILICON TRANSISTOR



ELECTRICAL CHARACTERISTICS - Continued: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MAX	UNITS
NF	$V_{CE}=5.0\text{V}$, $I_C=10\mu\text{A}$, $R_S=10\text{k}\Omega$ $BW=15.7\text{kHz}$, 3.0dB PTS @ 10Hz, 10kHz	3.0	dB
NF	$V_{CE}=5.0\text{V}$, $I_C=10\mu\text{A}$, $R_S=10\text{k}\Omega$, $f=100\text{Hz}$, $BW=20\text{Hz}$	10	dB
NF	$V_{CE}=5.0\text{V}$, $I_C=10\mu\text{A}$, $R_S=10\text{k}\Omega$, $f=1.0\text{kHz}$, $BW=200\text{Hz}$	3.0	dB
NF	$V_{CE}=5.0\text{V}$, $I_C=10\mu\text{A}$, $R_S=10\text{k}\Omega$, $f=10\text{kHz}$, $BW=2.0\text{kHz}$	2.0	dB

TO-18 CASE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A (DIA)	0.209	0.230	5.31	5.84
B (DIA)	0.178	0.195	4.52	4.95
C	-	0.030	-	0.76
D	0.170	0.210	4.32	5.33
E	0.500	-	12.70	-
F (DIA)	0.016	0.019	0.41	0.48
G (DIA)	0.100	-	2.54	-
H	0.050	-	1.27	-
I	0.036	0.046	0.91	1.17
J	0.028	0.048	0.71	1.22

TO-18 (REV: R1)

LEAD CODE:

- 1) Emitter
- 2) Base
- 3) Collector

MARKING:
FULL PART NUMBER

R1 (30-May 2012)

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1. If requesting Tin/Lead plated devices, add the suffix " TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
2. If requesting Lead (Pb) Free plated devices, add the suffix " PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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